

MOS FIELD EFFECT TRANSISTOR 2SK3386

ORDERING INFORMATION

PART NUMBER

2SK3386

2SK3386-Z

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3386 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low On-state Resistance R_{DS(on)1} = 21 mΩ MAX. (V_{GS} = 10 V, I_D = 17 A) R_{DS(on)2} = 36 mΩ MAX. (V_{GS} = 4.0 V, I_D = 17 A)
- Low Ciss : Ciss = 2100 pF TYP.
- Built-in Gate Protection Diode
- TO-251/TO-252 package

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

	• •		
Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	ID(DC)	±34	А
Drain Current (Pulse) ^{Note1}	D(pulse)	±120	А
Total Power Dissipation (Tc = 25°C)	Pτ	40	W
Total Power Dissipation (T _A = 25°C)	Pτ	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	28	А
Single Avalanche Energy Note2	Eas	78	mJ



PACKAGE

TO-251 (MP-3)

TO-252 (MP-3Z)



(TO-252)



Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

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The mark \star shows major revised points.

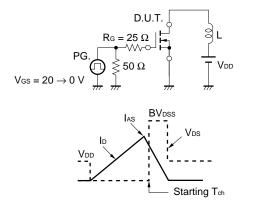
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ibss	V _{DS} = 60 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	lgss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 17 A	10	19		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 17 A		17	21	mΩ
	RDS(on)2	V _{GS} = 4.0 V, I _D = 17 A		25	36	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		2100		pF
Output Capacitance	Coss	V _{GS} = 0 V		340		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		170		pF
Turn-on Delay Time	td(on)	V _{DD} = 30 V, I _D = 17 A		32		ns
Rise Time	tr	V _{GS} = 10 V		310		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		98		ns
Fall Time	tr			100		ns
Total Gate Charge	QG	V _{DD} = 48 V		39		nC
Gate to Source Charge	QGS	V _{GS} = 10 V		7.0		nC
Gate to Drain Charge	Qgd	I _D = 34 A		12		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 34 A, VGS = 0 V		0.87		V
Reverse Recovery Time	trr	IF = 34 A, VGS = 0 V		46		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		84		nC

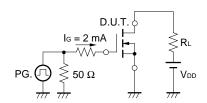
Note Pulsed

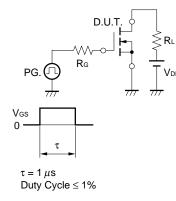
TEST CIRCUIT 1 AVALANCHE CAPABILITY

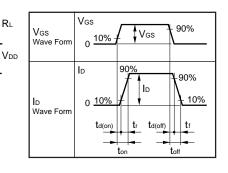
TEST CIRCUIT 2 SWITCHING TIME



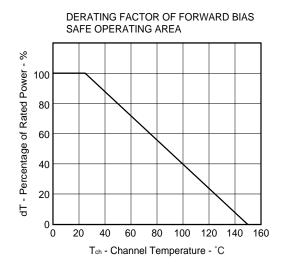
TEST CIRCUIT 3 GATE CHARGE



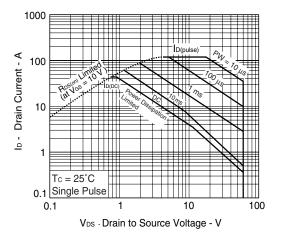




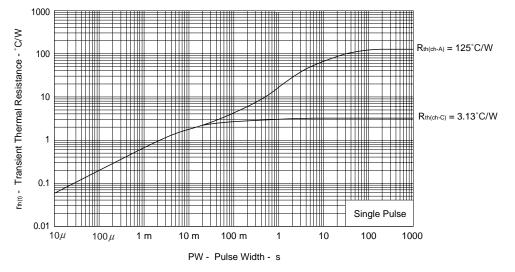
TYPICAL CHARACTERISTICS (TA = 25°C)

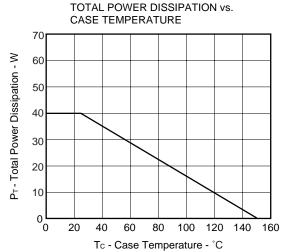




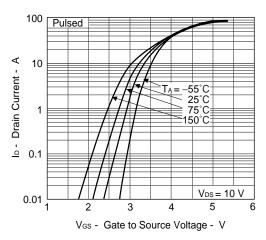


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

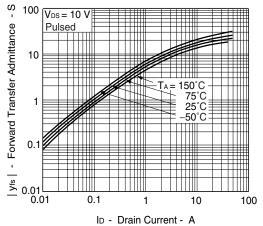


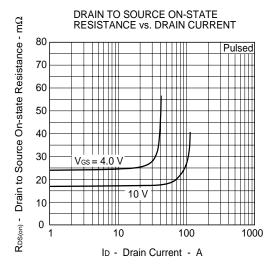


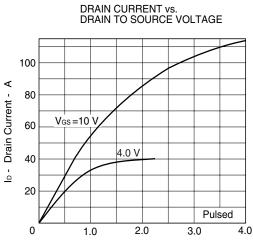
FORWARD TRANSFER CHARACTERISTICS



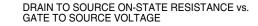


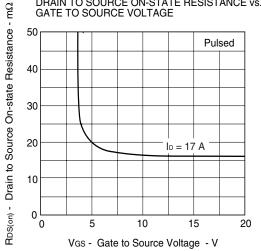




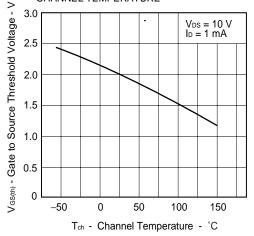


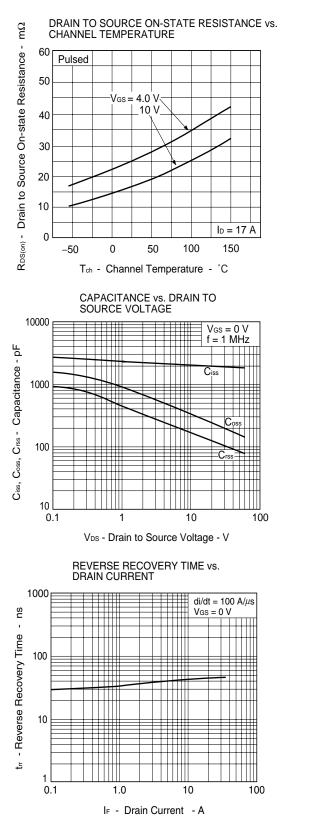
VDS - Drain to Source Voltage - V

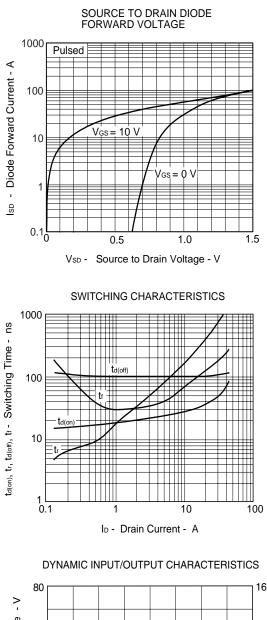


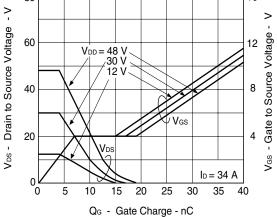


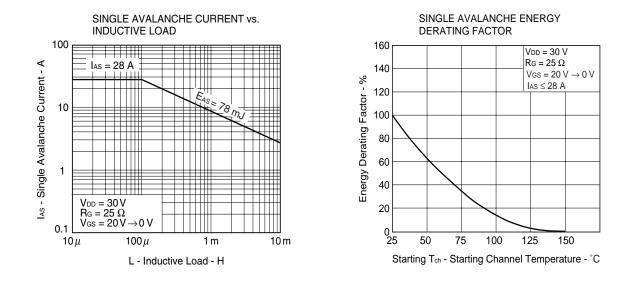
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE





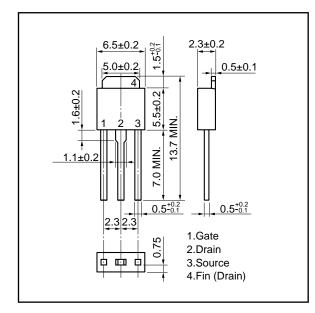


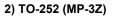


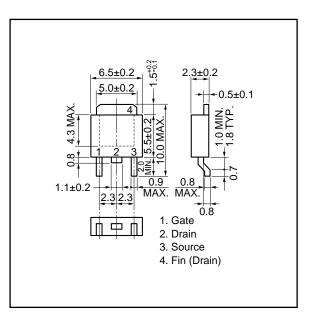


PACKAGE DRAWINGS (Unit: mm)

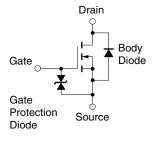
★ 1) TO-251 (MP-3)







EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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